Form PTO 1449		U.S. DEPARTMENT	OF COMMERCE	ATTY DOCKET NO.		SERIAL NO.				
(Modified)		PATENT AND TRAD	EMARK OFFICE	248442US0		NEW APPLICATION				
			APPLICANT							
LIST OF REFERENCES CITED BY APPLICANT				Toshiya SAGISAKA, et al.						
				FILING DATE		GROUP				
·			HEREWITH							
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EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE			
N N	AA	6,492,079	12/10/02	SHIMADA, ET AL.	·					
	AB	6,596,449	07/22/03	SHIMADA, ET AL.						
	AC	4,892,949	01/09/90	SASAKI	-					
	AD	4,859,556	08/22/89	SASAKI	_			······································		
	AE	5,840,454	11/24/98	NAGAI, ET AL.			***************************************			
	AF	6,018,014	01/25/00	NAGAI, ET AL.						
	AG	6,187,494	02/13/01	KAWAMURA, ET AL.						
TX.	AH	6,303,736	10/16/01	KAWAMURA, ET AL.						
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M	AJ	10-310635	11/24/98	JAPAN / w abstract		16.	,	140		
	AK	08-157575	06/18/96	JAPAN / w abstract						
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 	AN	11-195790	07/21/99	JAPAN / w abstract		 				
	AO	58-198425	11/18/83					······································		
}		·····		JAPAN / w abstract				 		
 	AP	58-198043	11/17/83	JAPAN / w abstract		ļ				
1	AQ	60-098437	06/01/85	JAPAN / w abstract		ļ				
100	AR	WO97/09394	03/13/97	WIPO		ļ		······································		
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Form PTO 1449 (Modified)			U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY DOCKET NO.	SERIAL NO.						
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